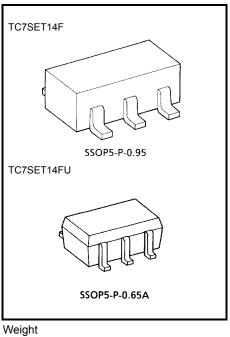
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SET14F,TC7SET14FU

Schmitt Inverter

Features

- High speed $t_{pd} = 5.0 \text{ ns (typ.)}$
 - at $V_{CC} = 5 V$
- Low power dissipation ICC = 2 μA (max) at Ta = 25°C
- Compatible with TTL outputs.
- 5.5V tolerant input.

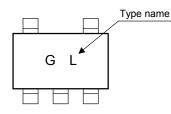


SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

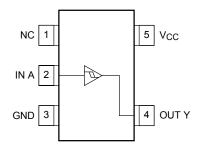
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7.0	V
DC input voltage	VIN	-0.5~7.0	V
DC output voltage	VOUT	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	200	mW
Storage temperature	T _{stg} –65~150		°C
Lead temperature (10 s)	TL	260	°C

Marking

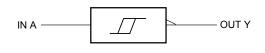


Pin Assignment (top view)



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Logic Diagram



INPUT	OUTPUT			
А	Y			
L	Н			
Н	L			

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	Vout	0~Vcc	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~20	ns/V

DC Electrical Characteristics

					Ta = 25°C		Ta = -40~85°C			
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Positive Threshold	VP			4.5	_	_	1.90		1.90	
Voltage	٧Þ		-	5.5	_		2.10	_	2.10	
Negative Threshold	Ve.			4.5	0.50	_	_	0.50	_	V
Voltage	V _N	_	-	5.5	0.60	_	_	0.60	_	v
	M	_		4.5	0.40	_	1.40	0.40	1.40	
Hysteresis voltage	Hysteresis Voltage V _H			5.5	0.40	_	1.50	0.40	1.50	
High-level output voltage	Vou		$I_{OH} = -50 \ \mu A$	4.5	4.4	4.5		4.4	_	v
High-level output voltage	High-level output voltage V _{OH}	$V_{IN} = V_{IL}$	$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	
Low-level output voltage	Vol		$I_{OL} = 50 \ \mu A$	4.5	_	0.0	0.10		0.10	
Low-level output voltage		$V_{IN} = V_{IH}$	$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36		0.44	
Input leakage current	I _{IN}	$V_{IN} = 5.5 V \text{ or } GND$		0~ 5.5	_	_	±0.1	_	±1.0	μA
	ICC	I_{CC} $V_{IN} = V_{CC}$ or GND		5.5	_	_	2.0		20.0	μA
Quiescent supply current	ICCT	Per Input Other Input	:V _{IN} = 3.4 V :V _{CC} or GND	5.5		_	1.35		1.50	mA

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics	Symbol		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	t _{pLH}	t _{oLH}	5.0 ± 0.5	15	_	5.0	7.6	1.0	9.0	ns
Fropagation delay time	tpHL			50	_	6.5	9.6	1.0	11.0	
Input capacitance	CIN				_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	18	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

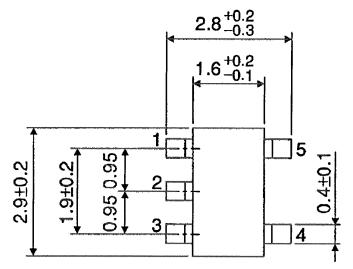
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

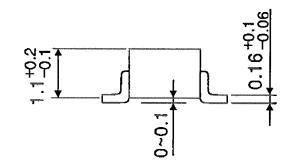
TOSHIBA

Package Dimensions



Unit : mm



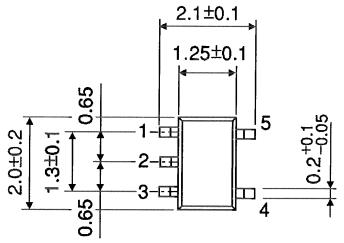


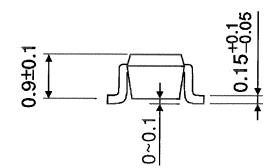
Weight: 0.016 g (typ.)

Package Dimensions

SSOF	P5-P-0	.65A
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Unit : mm





Weight: 0.006 g (typ.)

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030619EBA

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